



October 1987
Revised January 1999

MM74C32 Quad 2-Input OR Gate

General Description

The MM74C32 employs complementary MOS (CMOS) transistors to achieve low power and high noise margin, these gates provide the basic functions used in the implementation of digital integrated circuit systems. The N- and P-channel enhancement mode transistors provide a symmetrical circuit with output swings essentially equal to the supply voltage. This results in high noise immunity over a wide supply voltage range. No DC power other than that caused by leakage current is consumed during static con-

ditions. All inputs are protected against static discharge damage.

Features

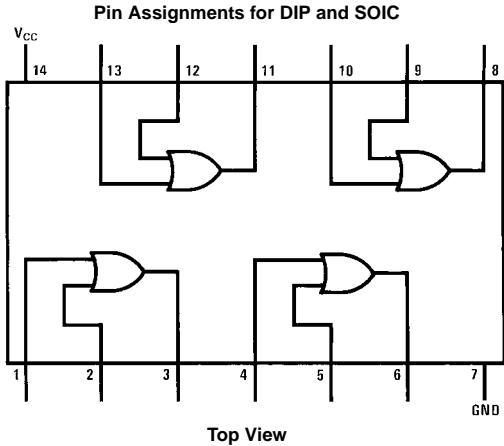
- Wide supply voltage range: 3.0V to 15V
- Guaranteed noise margin: 1.0V
- High noise immunity: 0.45V V_{CC} (typ.)
- Low power TTL compatibility: fan out of 2 driving 74L

Ordering Code:

Order Number	Package Number	Package Description
MM74C32M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
MM74C32N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



MM74C32 Quad 2-Input OR Gate

Absolute Maximum Ratings(Note 1)

Voltage at Any Pin	-0.3V to $V_{CC} + 0.3V$
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	-65°C to +150°C
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V_{CC} Range	3.0V to 15V

Absolute Maximum V_{CC}

18V

Lead Temperature

(Soldering, 10 seconds)

260°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics table provides conditions for actual device operation.

DC Electrical Characteristics

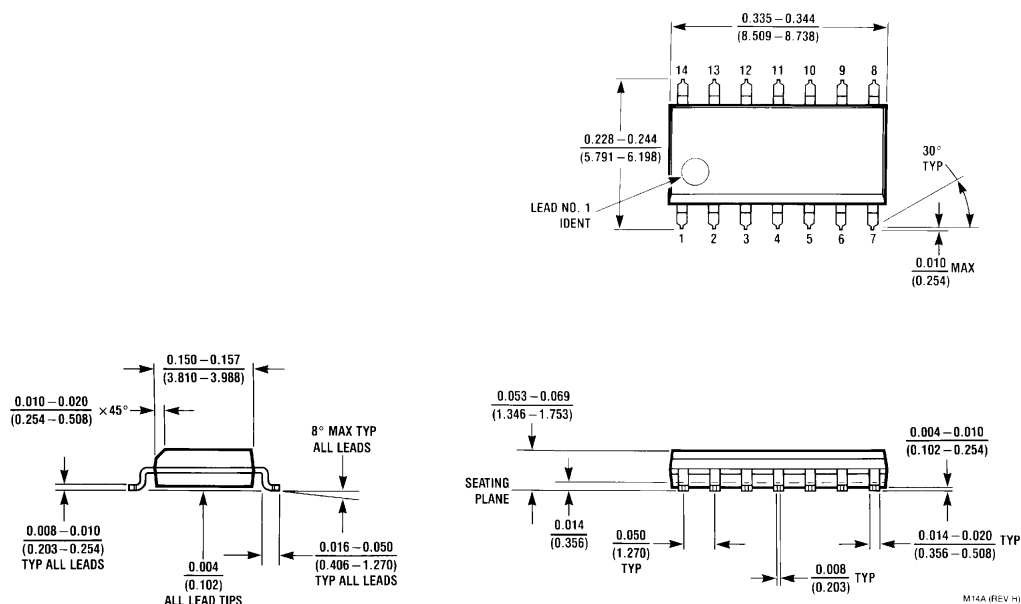
Min/Max limits apply across temperature range unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
CMOS TO CMOS						
$V_{IN(1)}$	Logical "1" Input Voltage	$V_{CC} = 5.0V$	3.5			V
		$V_{CC} = 10V$	8.0			V
$V_{IN(0)}$	Logical "0" Input Voltage	$V_{CC} = 5.0V$			1.5	V
		$V_{CC} = 10V$			2.0	V
$V_{OUT(1)}$	Logical "1" Output Voltage	$V_{CC} = 5.0V, I_O = -10 \mu A$	4.5			V
		$V_{CC} = 10V, I_O = -10 \mu A$	9.0			V
$V_{OUT(0)}$	Logical "0" Output Voltage	$V_{CC} = 5.0V, I_O = 10 \mu A$			0.5	V
		$V_{CC} = 10V, I_O = 10 \mu A$			1.0	V
$I_{IN(1)}$	Logical "1" Input Current	$V_{CC} = 15V, V_{IN} = 15V$		0.005	1.0	μA
$I_{IN(0)}$	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005		μA
I_{CC}	Supply Current	$V_{CC} = 15V$		0.05	15	μA
CMOS/LPTTL INTERFACE						
$V_{IN(1)}$	Logical "1" Input Voltage	$V_{CC} = 4.75V$	$V_{CC} - 1.5$			V
$V_{IN(0)}$	Logical "0" Input Voltage	$V_{CC} = 4.75V$			0.8	V
$V_{OUT(1)}$	Logical "1" Output Voltage	$V_{CC} = 4.75V, I_O = -360 \mu A$	2.4			V
$V_{OUT(0)}$	Logical "0" Output Voltage	$V_{CC} = 4.75V, I_O = 360 \mu A$			0.4	V
OUTPUT DRIVE (see Family Characteristics Data Sheet) $T_A = 25^\circ C$ (short circuit current)						
I_{SOURCE}	Output Source Current (P-Channel)	$V_{CC} = 5.0V, V_{OUT} = 0V$	-1.75	-3.3		mA
I_{SOURCE}	Output Source Current (P-Channel)	$V_{CC} = 10V, V_{OUT} = 0V$	-8.0	-15		mA
I_{SINK}	Output Sink Current (N-Channel)	$V_{CC} = 5.0V, V_{OUT} = V_{CC}$	1.75	3.6		mA
I_{SINK}	Output Sink Current (N-Channel)	$V_{CC} = 10V, V_{OUT} = V_{CC}$	8.0	16		mA

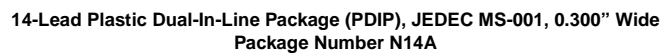
AC Electrical Characteristics (Note 2) $T_A = 25^\circ C, C_L = 50 \text{ pF}$, unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
t_{pd}	Propagation Delay Time to Logical "1" or "0"	$V_{CC} = 5.0V$		80	150	ns
		$V_{CC} = 10V$		35	70	ns
C_{IN}	Input Capacitance	Any Input (Note 3)		5		pF
C_{PD}	Power Dissipation Capacitance	Per Gate (Note 4)		15		pF

Note 2: AC Parameters are guaranteed by DC correlated testing.**Note 3:** Capacitance is guaranteed by periodic testing.**Note 4:** C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics Application Note—AN-90.

Physical Dimensions inches (millimeters) unless otherwise noted


**14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A**



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